Abstract — This paper presents a comparison on second and third order nonlinearity effects in Gilbert mixer and its variants, which are present in the majority wideband receivers. The implementations are made using bipolar transistors and are based on CMOS existing designs. The reason for using bipolar transistors is due to a larger transconductance and lower noise they have compared with MOS devices. We investigate about distortion sources and its effects on reception, and also the new design trends developed to compensate them. Simulations results show that Gilbert mixer with a cross-connected differential input pair has fewer output harmonics if compared with other designs. However, it presents a lower dynamic range. Also, parallel transistors input design shows fewer amplitude in harmonic components and intermodulation compared with the resistive and inductive emitter degeneration topology. This last topology retains the same advantages and disadvantages to their similar CMOS equivalent.

Keywords — Mixer, IP3, distortion, Gilbert.

1. INTRODUCTION

When talking about mixers, we are used to classify them in many different types. A possible classification considers mixers as [1], [4], [11], [12], [13]: actives, passives, and linear (time-invariant, time-variant) or nonlinear.

The Gilbert mixer [7], belongs to the linear time-invariant mixers class. Figure 1 shows a typical Gilbert mixer circuit where the local oscillator (LO) signal is applied to a differential pair of transistors which act as switches. That allows the current flow through them in alternating form. When BJT4 and BJT5 are on, BJT1 is connected with R3 and BJT2  is connected with R2. When BJT3 and BJT6 are on, the situation is inverted.

Assuming the circuit is perfectly symmetric and balanced, the intermediate frequency (IF) output will be equal in magnitude to the previous case, but inverted 180º in phase, i.e., is multiplied by -1.

The operation described above, can be formally explained if we consider a square wave signal applied to the LO. Such signal has a Fourier series representation given by [16]:

\[ v_{LO}(t) = 4 \sum_{n=1}^{\infty} \frac{(-1)^{n-1}}{2n-1} \cos[2\pi f_{LO}(2n-1)] \]  

(1)

Considering that the RF input is given by:

\[ v_{RF}(t) = V_{RF} \cos(2\pi f_{RF}t) \]  

(2)

Then, multiplying the \( v_{LO}(t) \) and \( v_{RF}(t) \) equations, we obtain:

\[ v_{out}(t) = 4 \sum_{n=1}^{\infty} \frac{(-1)^{n-1}}{2n-1} \cos[2\pi f_{LO}(2n-1)] \cdot V_{RF} \cos(2\pi f_{RF}t) \]  

(3)

Expanding eq. (3) by means of trigonometric identities, we found that the mixer output spectral composition consists of odd mixed products of RF and LO signals. That means that the Gilbert mixer shown in Figure 1 does deliver neither LO and RF signals nor even order harmonic products at the output. That is the main characteristic of the Gilbert mixer.

Mixers topologies analysed in this work are based on existing metal-oxide semiconductor field effect transistor (MOSFET) circuits. This paper proposes to evaluate the circuits’ performance using bipolar junction transistors (BJT) instead of MOSFET transistors. Each circuit is biased using the same current source topology in order to obtain independence of that part of the topology.

This paper is organized as follows. Section 2 explains the mixer conversion operation based on its nonlinear behaviour and the relationship with transistor parameters. Section 3 describes what linearity means in mixers and problems related with them. Section 4 presents the topologies analysed, which includes resistive emitter degeneration, inductive emitter degeneration, design with parallel transistors at the RF input and a modified version of Gilbert mixer. Schematics and simulation results are also presented in this section. Conclusions and comparisons are presented in section 5.
2. MIXER CONVERSION OPERATION

Any mixer working as frequency converter bases its operation on a generic nonlinearity, which can be expressed as [8], [9], [14]:

\[ i(t) = a_0 + a_1 v(t) + a_2 v(t)^2 + a_3 v(t)^3 + \ldots \]  \hspace{1cm} (4)

where \( i(t) \) is the output current, \( a_i \) are coefficients of a series expansion and \( v(t) \) is the input voltage applied to the device.

Eq. (4) can be analysed in more detail by giving to \( v(t) \) a voltage composed by two sinusoidal tones with frequencies \( \omega_1 \) and \( \omega_{LO} \) [5], [14]. Such tones can for example, represent the desired RF and LO signals going into the mixer. Consequently, \( v(t) \) can be written as:

\[ v(t) = \cos(\omega_1 t) + \cos(\omega_{LO} t) \]  \hspace{1cm} (5)

Replacing eq. (5) into eq. (4) produce:

\[ i(t) = a_0 + a_1 \cos(\omega_1 t) + \cos(\omega_{LO} t)) + a_2 (\cos(\omega_1 t) + \cos(\omega_{LO} t))^2 + \ldots \]  \hspace{1cm} (6)

Expanding eq. (6), we obtain tones in \( \cos(\omega_{L_{1\pm n}} + k \omega_1 + q \omega_{LO} t) \), where \( l, k \) and \( q \) are integers. In this case, there are a greater number of components due to the mixer nonlinearity. Since some of them will be very close the frequency band of interest they will be hard to remove by filtering. Therefore, it is necessary to take control of nonlinear mixer behavior.

Depending on the technology of the device considered, eq. (4) may change to different forms. In MOSFETs transistors, the drain current signal is given by [3], [6]:

\[ i_D(t) = \frac{\partial i_D}{\partial v_{GS}} v_{gs}(t) + \frac{\partial i_D}{\partial v_{BS}} v_{bs}(t) + \frac{\partial i_D}{\partial v_{DS}} v_{ds}(t) \]  \hspace{1cm} (8)

where \( i_D \) is drain current and \( v_{GS}, v_{BS} \) and \( v_{DS} \) are gate-source, bulk-source and drain-source, voltages respectively. By associating derivative terms as transconductance factors, eq. (8) can be written as:

\[ i_D(t) = gm v_{gs}(t) + gmb v_{bs}(t) + gds v_{ds}(t) \]  \hspace{1cm} (9)

Reversing eq. (7) into eq. (4) and expanding, we obtain components in \( \pm l \omega_{LO} \pm k \omega_1 \pm q \omega_{LO} \), where \( l, k \) and \( q \) are integers. In this case, there are a greater number of components due to the mixer nonlinearity. Since some of them will be very close the frequency band of interest they will be hard to remove by filtering. Therefore, it is necessary to take control of nonlinear mixer behavior.

In that case, it is assumed working on the receiver side. Therefore, the signal driven in the input circuit is assumed small enough to consider a weak nonlinearity only. Such assumption allows expanding eq. (8) into Taylor series as shown in eq. (10), where again, derivatives of order \( i \) were replaced by transconductance factors of order \( i [8] \):

\[ i_D = gm_1 v_{gs} + gm_2 v_{gs}^2 + gm_3 v_{gs}^3 + gmb_1 v_{bs} + gmb_2 v_{bs}^2 + gmb_3 v_{bs}^3 + gds_1 v_{ds} + gds_2 v_{ds}^2 + gds_3 v_{ds}^3 + \ldots \]  \hspace{1cm} (10)

On doing a frequency shift, only the first term is important because it produces the sum and difference components usually employed at the mixer output.

A similar analysis can be made in BJTs considering the operation at the point Q, as represented in Figure 2 [17].
At the point Q, the collector current is given by:

\[ i_C(v_{be}) = I_C + i_c(v_{be}) \]  

(11)

where \( I_C \) is the DC collector current and \( i_c \) is the signal collector current. Expanding eq. (11) into Taylor series, we obtain:

\[
 i_C(v_{be}) = I_C + \left( \frac{\partial I_C}{\partial v_{BE}} \right) v_{be} + \left( \frac{1}{2!} \frac{\partial^2 I_C}{\partial v_{BE}^2} \right) v_{be}^2 + \left( \frac{1}{3!} \frac{\partial^3 I_C}{\partial v_{BE}^3} \right) v_{be}^3 + ... 
\]

(12)

By associating the terms in parentheses as transconductance factors, eq. (12) can be written as:

\[
 i_c(v_{be}) = I_C + g_{m1} v_{be} + g_{m2} v_{be}^2 + g_{m3} v_{be}^3 + ... 
\]

(13)

The factor \( g_{m1} \) is the first order transconductance that represents the device’s transfer characteristic slope at the point Q. A very common expression for such a factor is [17]:

\[
 g_{m1} = \frac{I_C}{V_T} 
\]

(14)

where \( I_C \) is the DC collector current and \( V_T \) is the thermal voltage (25.2 mV at 20ºC). Therefore, the signal current can be approximated by the second term in eq. (13) as:

\[
 i_c(t) = g_{m1} v_{be}(t) = \frac{I_C}{V_T} v_{be}(t) 
\]

(15)

Eq. (13) is similar to that found in MOSFETs. As a consequence, similar considerations about the effects of each term in the mixing can be made.

Figure 3 shows the first, second and third order transconductances versus \( v_{BE} \) for a typical bipolar transistor. As can be seen in that figure, there is a \( v_{BE} \) value about 0.805 V for which the third order transconductance is near to zero. This is a desired operating point because it reduces an important intermodulation distortion.

3. MIXER LINEARITY

Linearization of a mixer refers to forcing proportionality between IF output and RF input signals. The main parameter to quantify linearity is the third-order intercept point (IP3). IP3 is a figure of merit that allows characterize the intermodulation distortion in a circuit by considering the cross point where the linear extrapolation of the fundamental signal equals the linear extrapolation of the third order harmonic [1], [2], [11]. It means a mixer is more linear when the IP3 becomes higher because less intermodulation products are generated.

In general, a circuit is linear when it fulfills the superposition principle [9], [11]. Following section 2, the basic principle of the mixer is nonlinear. The linearity requirement is related to input transistors differential pair. Every time “linearity of the mixer” is mentioned, it is referred to RF inputs. The LO signal is only necessary for frequency shifting but actually it is not desired at the output.

As mentioned before, mixer linearity is related to the amount of spurious products generated at the output. Ideal Gilbert mixer is a symmetric circuit which does not produce components of second order to the output. However, any difference in the symmetry of the circuit causes second order intermodulation distortion (IMD2) due to unbalanced currents that reach the load.

Other nonlinearity to have in mind is that of third order which is the most important. It is responsible for the third order intermodulation distortion (IMD3) caused by the RF input transistors. A minor contribution to IMD3 is the commutation of upper differential pairs. Some techniques compensate third order transconductance (\( g_{m3} \)) by combining similar transistors in parallel using slightly different biases. Using that technique is possible to cancel \( g_{m3} \) in the proximity of \( v_{BE} \) considering BJTs or \( v_{GS} \) considering MOSFETs. Other techniques employ
pre-distortion on the RF signal to compensate nonlinearities [18].

With reference to circuits, the linearity allows to operate with large dynamic range signals, something that in modern communication standards is used frequently, without introduce significantly distortion at the output.

4. COMPENSATION TECHNIQUES

PERFORMANCE

All circuits were made in Agilent’s ADS (Advanced Design System) software at $\omega_{RF} = 2.4$ GHz, $\omega_{LO} = 2.45$ GHz and $\omega_{IF} = 50$ MHz. Each technique was evaluated using IHP’s SG25 library devices. For each topology, it is simulated the output power at the IF port showing the 1dB compression point to determine the linear operation limit. The conversion gain is also plotted as a function of RF power to analyze how the modifications change the performance gain. Finally, the output spectrum is simulated to evaluate the linearization effects on the harmonics and IMD products.

4.1. Resistive emitter degeneration

It is the classic Gilbert mixer configuration which includes resistors at the emitter of input differential pair. The objective is to introduce some feedback in the lower differential pair aiming to increase linearity, as shown in Figure 4(a). However, the feedback disadvantages are gain loss and increased noise [4]. Figure 4(b) shows the IF spectrum, which has components very close to the desired output frequency (50 MHz). In part (c) of Figure 4 is plotted the conversion gain versus input power. We can see the gain is nearly constant for small level inputs (lower than -20 dB). Figure 4(d) shows the output power response to expose the mixer nonlinear behaviour as a function of input power. The vertical line indicates the 1 dB compression point to emphasize the point where the fundamental output curve is 1 dB lower than predicted by the ideal output curve.

4.2. Inductive emitter degeneration

It is the same configuration that in Figure 4(a) but considering $RS = 0$ and $LS = 1.3$ nH. The advantage of replacing the resistor by an inductor consists in the little voltage drop in the inductor due to current bias, which is important if the design must work at low voltage. However, the main disadvantage of inductive degeneration is the operation of the design, which will depend on the frequency. The results are shown in Figure 5. In part (a) of that figure, is shown the output spectrum. If compared with Figure 4(b), it can be seen a reduction in the first spectral line close to the fundamental output at 50 MHz. Figure 5(b) shows that the conversion gain is reduced for about 1.2 dB at the 1 dB compression point compared with the mixer with emitter resistor degeneration. In Figure 5(c), the output power versus input power is shown. The output power at the 1 dB compression point is -20.9 dBm, which is 0.3 dBm greater than the previous circuit.
Figure 5. Simulations results for Gilbert mixer with inductive emitter degeneration (SRL1 = 0 Ω, 1.3 nH). (a) IF output spectrum. (b) Conversion gain vs. RF power: PRF 1dB: -15.8 dBm, Gain 1dB: -5.1 dB. (c) IF power vs. RF power: PIF 1dB: -20.9 dBm, PIF ideal: -19.9 dBm.

4.3. Design with Parallel transistors at the RF input

This is a modification made in [15]. The focus is linearizing the third order transconductance by reducing its negative peak with the positive peak of the third order transconductance of another transistor in parallel with the first. The circuit and simulations are shown in Figure 6.

Figure 6: (a) Gilbert mixer with parallel transistors at input. (b) IF output spectrum. (c) Conversion gain vs. RF power: PRF 1dB: -13.4 dBm, Gain 1dB: -6.7 dB. (d) IF power vs. RF power: PIF 1dB: -20.1 dBm, PIF ideal: -19.1 dBm.

Figure 6(b) shows the spectral output where it can be appreciated a greater reduction in the first spectral line compared with the mixer with inductive emitter degeneration and also a reduction in the harmonics levels at 2.4 GHz and 2.5 GHz. Figure 6(c) shows that the conversion gain is -6.7 dB, 0.4 dB lower than the resistive emitter degeneration and 1.6 dB lower than the inductive emitter degeneration. However, as shown in Figure 6(d), the input power level at the compression point is higher, which means the input dynamic range is also higher.

4.4. Modified Gilbert mixer

It is the modification made in [10] for MOSFETs and adapted here to BJT design, as shown in Figure 7. In this case, the idea is to employ the same configuration used at the LO input but at the RF input. Simulation results show in Figure 7(b) the output spectrum is greatly reduced. It can be seen the spectral line at 100 MHz has disappeared as well as the harmonics at 2.4 GHz and 2.5 GHz. However, these benefits are at the expense of conversion gain, as shown in Figure 7(c). Finally, in Figure 7(d) is appreciated that the input power at the 1dB compression point is the lower of all considered.
Gilbert mixer commutation linearity is mainly affected by the transconductance of RF input differential pair. The transistors of the upper differential pair where the LO signal is applied, do not introduce a large IM distortion at the output despite the fact that they are working as commutation devices. However, they are responsible of generation of multiple RF and LO odd harmonics at the output in the GHz range. This does not affect the system linearity because they may be filtered out. Using quadratic law devices such as FETs instead of bipolar transistors may help to reduce spurious effects at the output.

As a future work, it is proposed to combine BJTs and MOSFETs in a same mixer circuit with the purpose of evaluating the characteristics and performance.

REFERENCES

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5. CONCLUSIONS

Gilbert mixer commutation linearity is mainly affected by the transconductance of RF input differential pair.